## **AMENDMENTS TO THE CLAIMS:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

- 1. (Currently Amended) A plasma treatment apparatus comprising:
- a plasma generation unit comprising a first electrode and a plurality of second electrodes opposed to the first electrode;
- a gas supply unit [[for]] <u>adapted to blow</u> <del>blowing</del> a process gas into a space between the first electrode and the plurality of second electrodes; and
- a unit [[for]] <u>adapted to</u> selectively <u>apply</u> <del>applying</del> a voltage to at least one electrode among the plurality of second electrodes,
- wherein the plurality of second electrodes are arranged linearly in one line or a plurality of lines, and

wherein the first electrode and the plurality of second electrodes are arranged perpendicular to a subject substrate.

- 2. (Currently Amended) A plasma treatment apparatus comprising:
- a plasma generation unit comprising a first electrode and a plurality of second electrodes opposed to the first electrode;
- a gas supply unit [[for]] <u>adapted to blow</u> <u>blowing</u> a process gas into a space between the first electrode and the plurality of second electrodes; and
- a unit [[for]] <u>adapted to</u> selectively <u>apply</u> <del>applying</del> a voltage to at least one electrode among the plurality of second electrodes,
- wherein the plurality of second electrodes are arranged linearly in one line or a plurality of lines; and.
- wherein at least one of the plurality of second electrodes has a length of equal to or less than 1 mm on a side of an object to be treated, and

wherein the first electrode and the plurality of second electrodes are arranged perpendicular to a subject substrate.

- 3. (Currently Amended) A plasma treatment apparatus comprising:
- a plasma generation unit comprising a first electrode and a plurality of second

electrodes opposed to the first electrode [[for]] <u>adapted to form forming</u> a pattern on an object to be treated;

a gas supply unit [[for]] <u>adapted to blow blowing</u> a process gas into a space between the first electrode and the plurality of second electrodes; and

a unit [[for]] <u>adapted to</u> selectively <u>apply</u> <del>applying</del> a voltage to at least one electrode among the plurality of second electrodes,

wherein the plurality of second electrodes are arranged linearly in one line or a plurality of lines; and,

wherein at least one of the plurality of second electrodes has a length of equal to or less than a square of a line width of the pattern on a side of the object to be treated, and

wherein the first electrode and the plurality of second electrodes are arranged perpendicular to a subject substrate.

4. (Original) A plasma treatment apparatus according to claim 3, wherein the pattern is a wiring pattern.

## 5.-9. (Canceled)

- 10. (Previously Presented ) A plasma treatment apparatus according to claim 1, wherein the plurality of second electrodes are processed by using a focused ion beam apparatus, photolithography, or a laser lithography apparatus.
- 11. (Previously Presented) A plasma treatment apparatus according to claim 2, wherein the plurality of second electrodes are processed by using a focused ion beam apparatus, photolithography, or a laser lithography apparatus.
- 12. (Previously Presented) A plasma treatment apparatus according to claim 3, wherein the plurality of second electrodes are processed by using a focused ion beam apparatus, photolithography, or a laser lithography apparatus.
- 13. (Previously Presented) A plasma treatment apparatus according to claim 1, wherein the first electrode and the plurality of second electrodes are covered with a dielectric.

- 14. (Previously Presented) A plasma treatment apparatus according to claim 2, wherein the first electrode and the plurality of second electrodes are covered with a dielectric.
- 15. (Previously Presented) A plasma treatment apparatus according to claim 3, wherein the first electrode and the plurality of second electrodes are covered with a dielectric.
- 16. (Previously Presented) A plasma treatment apparatus according to claim 1, wherein the voltage is applied to the predetermined electrode for performing a film formation, an etching treatment, or a surface modification over an object to be treated.
- 17. (Previously Presented) A plasma treatment apparatus according to claim 2, wherein the voltage is applied to the predetermined electrode for performing a film formation, an etching treatment, or a surface modification over an object to be treated.
- 18. (Previously Presented) A plasma treatment apparatus according to claim 3, wherein the forming of the pattern is performed under atmospheric pressure or under pressure approximate to atmospheric pressure.
- 19. (Currently Amended) A plasma treatment apparatus according to claim 1 further comprising a stage to which an object to be treated is fixed,

20. (Previously Presented) A plasma treatment apparatus according to claim 2 further comprising a stage to which the object is fixed,

wherein a scanning of the stage is synchronized with the application of the voltage to the predetermined electrode.

21. (Previously Presented) A plasma treatment apparatus according to claim 3 further comprising a stage to which the object is fixed,

wherein a scanning of the stage is synchronized with the application of the voltage to

the predetermined electrode.

- 22. (Previously Presented) A plasma treatment apparatus according to claim 16, wherein the film formation, the etching treatment, or the surface modification is performed under atmospheric pressure or under pressure approximate to atmospheric pressure.
- 23. (Previously Presented) A plasma treatment apparatus according to claim 17, wherein the film formation, the etching treatment, or the surface modification is performed under atmospheric pressure or under pressure approximate to atmospheric pressure.
  - 24. (Currently Amended) A plasma treatment apparatus comprising:

a plurality of plasma generation units each comprising a first electrode and a <del>plurality</del> of second <u>electrode</u>;

a gas supply unit [[for]] <u>adapted to blow</u> <u>blowing</u> a process gas into a space between the first electrode and the plurality of second electrodes; and

a unit [[for]] <u>adapted to</u> selectively <u>apply</u> <del>applying</del> a voltage to at least one electrode among the <del>plurality of</del> second electrodes,

wherein the plurality of plasma generation units are arranged linearly in one line or a plurality of lines, and

wherein the first electrode and the second electrode are arranged perpendicular to a subject substrate.

- 25. (Previously Presented) A plasma treatment apparatus according to claim 24, wherein a relatively scanning of the plurality of plasma generation units is synchronized with the application of the voltage to the predetermined electrode.
- 26. (Previously Presented) A plasma treatment apparatus according to claim 24, wherein the plurality of second electrodes are processed by using a focused ion beam apparatus, photolithography, or a laser lithography apparatus.
- 27. (Previously Presented) A plasma treatment apparatus according to claim 24, wherein the first electrode and the plurality of second electrodes are covered with a dielectric.

- 28. (Previously Presented) A plasma treatment apparatus according to claim 24, wherein the voltage is applied to the predetermined electrode for performing a film formation, an etching treatment, or a surface modification over an object to be treated.
- 29. (Currently Amended) A plasma treatment apparatus according to claim 24 further comprising a stage to which an object to be treated is fixed,

- 30. (Previously Presented) A plasma treatment apparatus according to claim 28, wherein the film formation, the etching treatment, or the surface modification is performed under atmospheric pressure or under pressure approximate to atmospheric pressure.
  - 31. (Currently Amended) A plasma treatment apparatus comprising:

a plasma generation unit comprising a first electrode and a plurality of second electrodes opposed to the first electrode;

a gas supply unit [[for]] <u>adapted to blow</u> <del>blowing</del> a process gas to a substrate to be treated through a space between the first electrode and the plurality of second electrodes; and a unit [[for]] <u>adapted to</u> selectively <u>apply</u> <del>applying</del> a voltage to at least one electrode

among the plurality of second electrodes,

wherein the plurality of second electrodes are arranged linearly in one line or a plurality of lines, and

wherein the first electrode and the plurality of second electrodes are arranged perpendicular to a subject substrate.

## 32. (Canceled)

33. (Previously Presented ) A plasma treatment apparatus according to claim 31, wherein the plurality of second electrodes are processed by using a focused ion beam apparatus, photolithography, or a laser lithography apparatus.

- 34. (Previously Presented) A plasma treatment apparatus according to claim 31, wherein the first electrode and the plurality of second electrodes are covered with a dielectric.
- 35. (Previously Presented) A plasma treatment apparatus according to claim 31, wherein the voltage is applied to the predetermined electrode for performing a film formation, an etching treatment, or a surface modification over an object to be treated.
- 36. (Currently Amended) A plasma treatment apparatus according to claim 31 further comprising a stage to which an object to be treated is fixed,

- 37. (Previously Presented) A plasma treatment apparatus according to claim 35, wherein the film formation, the etching treatment, or the surface modification is performed under atmospheric pressure or under pressure approximate to atmospheric pressure.
  - 38. (Currently Amended) A plasma treatment apparatus comprising:

a plasma generation unit comprising a first electrode and a plurality of second electrodes opposed to the first electrode;

a gas supply unit [[for]] <u>adapted to blow blowing</u> a process gas through a first space and a second a second space continuously, the first space being between the first electrode and a substrate and the second space being between the plurality of second electrodes and the substrate; and

a unit [[for]] <u>adapted to</u> selectively <u>apply applying</u> a voltage to at least one electrode among the plurality of second electrodes,

wherein the plurality of second electrodes are arranged linearly in one line or a plurality of lines, and

wherein the first electrode and the plurality of second electrodes are arranged perpendicular to a subject substrate.

39. (Canceled)

- 40. (Previously Presented) A plasma treatment apparatus according to claim 38, wherein the plurality of second electrodes are processed by using a focused ion beam apparatus, photolithography, or a laser lithography apparatus.
- 41. (Previously Presented) A plasma treatment apparatus according to claim 38, wherein the first electrode and the plurality of second electrodes are covered with a dielectric.
- 42. (Previously Presented) A plasma treatment apparatus according to claim 38, wherein the voltage is applied to the predetermined electrode for performing a film formation, an etching treatment, or a surface modification over an object to be treated.
- 43. (Currently Amended) A plasma treatment apparatus according to claim 38 further comprising a stage to which an object to be treated is fixed,

- 44. (Previously Presented) A plasma treatment apparatus according to claim 42, wherein the film formation, the etching treatment, or the surface modification is performed under atmospheric pressure or under pressure approximate to atmospheric pressure.
- 45. (New) A plasma treatment apparatus according to claim 1, wherein the blown process gas acts on the subject substrate.
- 46. (New) A plasma treatment apparatus according to claim 2, wherein the blown process gas acts on the subject substrate.
- 47. (New) A plasma treatment apparatus according to claim 3, wherein the blown process gas acts on the subject substrate.
- 48. (New) A plasma treatment apparatus according to claim 24, wherein the blown process gas acts on the subject substrate.

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- 49. (New) A plasma treatment apparatus according to claim 31, wherein the blown process gas acts on the subject substrate.
- 50. (New) A plasma treatment apparatus according to claim 38, wherein the blown process gas acts on the subject substrate.
- 51. (New) A plasma treatment apparatus according to claim 1, wherein the plasma generation unit is adapted for movement in an X direction and a Y direction relative to the position of the subject substrate.
- 52. (New) A plasma treatment apparatus according to claim 2, wherein the plasma generation unit is adapted for movement in an X direction and a Y direction relative to the position of the subject substrate.
- 53. (New) A plasma treatment apparatus according to claim 3, wherein the plasma generation unit is adapted for movement in an X direction and a Y direction relative to the position of the subject substrate.
- 54. (New) A plasma treatment apparatus according to claim 24, wherein the plasma generation units are adapted for movement in an X direction and a Y direction relative to the position of the subject substrate.
- 55. (New) A plasma treatment apparatus according to claim 31, wherein the plasma generation unit is adapted for movement in an X direction and a Y direction relative to the position of the subject substrate.
- 56. (New) A plasma treatment apparatus according to claim 38, wherein the plasma generation unit is adapted for movement in an X direction and a Y direction relative to the position of the subject substrate.